Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

Send any inquiries to http://www.renesas.com/inquiry.



Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights
 of third parties by or arising from the use of Renesas Electronics products or technical information described in this document.
 No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights
 of Renesas Electronics or others.
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
 - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
 - "Specific": Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.



MOS INTEGRATED CIRCUIT $\mu PD720113$

USB 2.0 HUB CONTROLLER



The μ PD720113 is a USB 2.0 hub device that complies with the Universal Serial Bus (USB) Specification Revision 2.0 and works up to 480 Mbps. USB 2.0 compliant transceivers are integrated for upstream and all downstream ports. The μ PD720113 works backward compatible either when any one of the downstream ports is connected to a USB 1.1 compliant device, or when the upstream port is connected to a USB 1.1 compliant host.

Detailed function descriptions are provided in the following user's manual. Be sure to read the manual before designing. μ PD720113 User's Manual: S16619E

FEATURES

- Compliant with Universal Serial Bus Specification Revision 2.0 (Data Rate 1.5/12/480 Mbps)
- · Certified by USB implementers forum and granted the USB 2.0 high-speed Logo
- High-speed or full-speed packet protocol sequencer for Endpoint 0/1
- 7 (Max.) downstream facing ports
- All downstream facing ports can handle high-speed (480 Mbps), full-speed (12 Mbps), and low-speed (1.5 Mbps) transaction.
- Supports split transaction to handle full-speed and low-speed transaction on downstream facing ports when Hub controller is working in high-speed mode.
- One Transaction Translator per Hub and supports four non-periodic buffers
- · Support self-powered mode
- · Supports Over-current detection and Individual or ganged power control
- Supports configurable vendor ID, product ID, string descriptors and others with external Serial ROM
- Supports "non-removable" attribution on individual port
- Uses 30 MHz X'tal, or clock input
- 2.5 V and 3.3 V power supplies

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

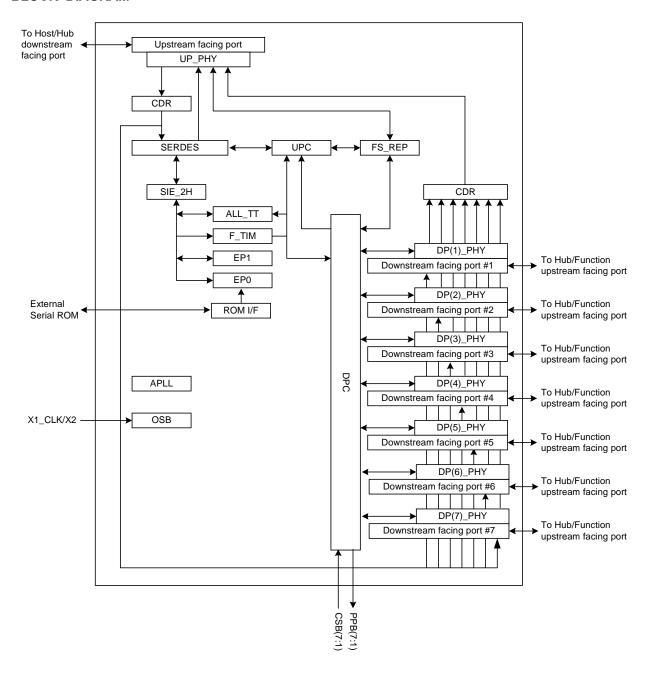
Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.



ORDERING INFORMATION

	Part Number	Package	Remark
	μPD720113GK-9EU	80-pin plastic TQFP (Fine pitch) (12 \times 12)	
*	μPD720113GK-9EU-A	80-pin plastic TQFP (Fine pitch) (12 \times 12)	Lead-free product

BLOCK DIAGRAM



NEC μ PD720113

APLL : Generates all clocks of Hub.

ALL_TT : Translates the high-speed transactions (split transactions) for full/low-speed device

to full/low-speed transactions. ALL_TT buffers the data transfer from either upstream or downstream direction. For OUT transaction, ALL_TT buffers data from upstream port and sends it out to the downstream facing ports after speed conversion from high-speed to full/low-speed. For IN transaction, ALL_TT buffers data from downstream ports and sends it out to the upstream facing ports after

speed conversion from full/low-speed to high-speed.

CDR : Data & clock recovery circuit

DPC : Downstream Port Controller handles Port Reset, Enable, Disable, Suspend and

Resume

DP(n)_PHY : Downstream transceiver supports high-speed (480 Mbps), full-speed (12 Mbps), and

low-speed (1.5 Mbps) transaction

EP0 : Endpoint 0 controller
EP1 : Endpoint 1 controller

F_TIM (Frame Timer) : Manages hub's synchronization by using micro-SOF which is received at upstream

port, and generates SOF packet when full/low-speed device is attached to

downstream facing port.

FS_REP : Full/low-speed repeater is enabled when the μ PD720113 are worked at full-speed

mode

OSB : Oscillator Block

ROM I/F : Interface block for external Serial ROM which contains user-defined descriptors

SERDES : Serializer and Deserializer

SIE 2H : Serial Interface Engine (SIE) controls USB2.0 and 1.1 protocol sequencer.

UP_PHY : Upstream Transceiver supports high-speed (480 Mbps), full-speed (12 Mbps)

transaction

UPC : Upstream Port Controller handles Suspend and Resume

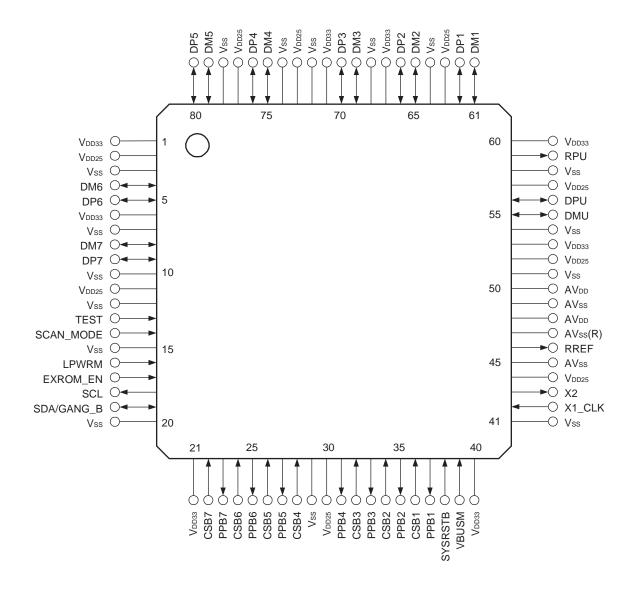


PIN CONFIGURATION (TOP VIEW)

• 80-pin plastic TQFP (Fine pitch) (12 × 12)

 μ PD720113GK-9EU

★ μPD720113GK-9EU-A





Pin No.	Pin Name						
1	V _{DD33}	21	V _{DD33}	41	Vss	61	DM1
2	V _{DD25}	22	CSB7	42	X1_CLK	62	DP1
3	Vss	23	PPB7	43	X2	63	V _{DD25}
4	DM6	24	CSB6	44	V _{DD25}	64	Vss
5	DP6	25	PPB6	45	AVss	65	DM2
6	V _{DD33}	26	CSB5	46	RREF	66	DP2
7	Vss	27	PPB5	47	AVss(R)	67	V _{DD33}
8	DM7	28	CSB4	48	AV _{DD}	68	Vss
9	DP7	29	Vss	49	AVss	69	DM3
10	Vss	30	V _{DD25}	50	AV _{DD}	70	DP3
11	V _{DD25}	31	PPB4	51	Vss	71	V _{DD33}
12	Vss	32	CSB3	52	V _{DD25}	72	Vss
13	TEST	33	PPB3	53	V _{DD33}	73	V _{DD25}
14	SCAN_MODE	34	CSB2	54	Vss	74	Vss
15	Vss	35	PPB2	55	DMU	75	DM4
16	LPWRM	36	CSB1	56	DPU	76	DP4
17	EXROM_EN	37	PPB1	57	V _{DD25}	77	V _{DD25}
18	SCL	38	SYSRSTB	58	Vss	78	Vss
19	SDA/GANG_B	39	VBUSM	59	RPU	79	DM5
20	Vss	40	V _{DD33}	60	V _{DD33}	80	DP5

Remark AVss(R) should be used to connect RREF through 1 % precision reference resistor of 2.43 k Ω .



1. PIN INFORMATION

Pin Name	I/O	Buffer Type	Active Level	Function
X1_CLK	1	2.5 V Input		Crystal oscillator in or clock input
X2	0	2.5 V Output		Oscillator out
SYSRSTB	1	5 V tolerant Schmitt Input	Low	Asynchronous chip reset
RPU	A (O)	USB Pull-up control		External 1.5 kΩ pull-up resistor control
DP(7:1)	I/O	USB D+ signal I/O		USB's downstream facing port D+ signal
DM(7:1)	I/O	USB D- signal I/O		USB's downstream facing port D- signal
DPU	I/O	USB D+ signal I/O		USB's upstream facing port D+ signal
DMU	I/O	USB D- signal I/O		USB's upstream facing port D– signal
LPWRM	1	3.3 V Schmitt Input		Local power monitor
RREF	A (O)	Analog		Reference resistor
CSB(7:1)	1	5 V tolerant Input	Low	Port's over-current status input
PPB(7:1)	0	5 V tolerant N-ch open drain	Low	Port's power supply control output
VBUSM	1	5 V tolerant Schmitt input		V _{BUS} monitor
SCL	0	3.3 V Output		External serial ROM clock out
SDA/GANG_B	I/O	3.3 V Schmitt I/O		External serial ROM data IO or power management mode select
EXROM_EN	1	3.3 V Schmitt Input		External serial ROM input enable
TEST	1	3.3 V Input		Test signal
SCAN_MODE	1	3.3 V Input		Test signal
V _{DD33}				3.3 V V _{DD}
V _{DD25}				2.5 V V _{DD}
AV _{DD}				2.5 V V _{DD} for analog circuit
Vss				Vss
AVss				Vss for analog circuit
AVss(R)				Vss for reference resistor. Connect to AVss.

Remark "5 V tolerant" means that the buffer is 3 V buffer with 5 V tolerant circuit.

2. ELECTRICAL SPECIFICATIONS

2.1 Buffer List

• 2.5 V Oscillator interface

X1_CLK, X2

• 5 V Schmitt input buffer

SYSRSTB, CSB(7:1), VBUSM

• 3.3 V Schmitt input buffer

LPWRM

• 3.3 V input buffer

EXROM_EN, TEST, SCAN_MODE

• 3.3 V IoL = 3 mA bi-directional Schmitt input buffer with input enable (OR-type)

SDA/GANG_B

• 3.3 V IoL = 3 mA output buffer

SCL

• 5 V IoL = 12 mA N-ch open drain buffer

PPB(7:1)

USB2.0 interface

RPU, DPU, DMU, DP(7:1), DM(7:1), RREF

Above, "5 V" refers to a 3 V input buffer that is 5 V tolerant (has 5 V maximum input voltage). Therefore, it is possible to have a 5 V connection for an external bus.



2.2 Terminology

Terms Used in Absolute Maximum Ratings

Parameter	Symbol	Meaning
Power supply voltage	VDD33 VDD25 AVDD	Indicates voltage range within which damage or reduced reliability will not result when power is applied to a V_{DD} pin.
Input voltage	Vı	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an input pin.
Output voltage	Vo	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an output pin.
Output current	lo	Indicates absolute tolerance values for DC current to prevent damage or reduced reliability when current flows out of or into an output pin.
Operating temperature	TA	Indicates the ambient temperature range for normal logic operations.
Storage temperature	Tstg	Indicates the element temperature range within which damage or reduced reliability will not result while no voltage or current are applied to the device.

Terms Used in Recommended Operating Range

Parameter	Symbol	Meaning
Power supply voltage	V _{DD33} V _{DD25} AV _{DD}	Indicates the voltage range for normal logic operations to occur when $V_{\rm SS}$ = 0 $V_{\rm SS}$
High-level input voltage	ViH	Indicates the voltage, applied to the input pins of the device, which indicates the high level state for normal operation of the input buffer.
		* If a voltage that is equal to or greater than the "MIN." value is applied, the input voltage is guaranteed as high level voltage.
Low-level input voltage	VIL	Indicates the voltage, applied to the input pins of the device, which indicates the low level state for normal operation of the input buffer.
		* If a voltage that is equal to or less than the "MAX." value is applied, the input voltage is guaranteed as low level voltage.
Hysteresis voltage	Vн	Indicates the differential between the positive trigger voltage and the negative trigger voltage.
Input rise time	tri	Indicates allowable input signal transition time from $0.1 \times V_{DD}$ to $0.9 \times V_{DD}$.
Input fall time	t fi	Indicates allowable input signal transition time from $0.9 \times V_{DD}$ to $0.1 \times V_{DD}$.



Terms Used in DC Characteristics

Parameter	Symbol	Meaning
Off-state output leakage current	loz	Indicates the current that flows into a 3-state output pin when it is in a high-impedance state and a voltage is applied to the pin.
Output short circuit current	los	Indicates the current that flows from an output pin when it is shorted to GND while it is at high-level.
Input leakage current	lı	Indicates the current that flows into an input pin when a voltage is applied to the pin.
Low-level output current	Ю	Indicates the current that can flow into an output pin in the low-level state without raising the output voltage above the specified Vol.
High-level output current	Іон	Indicates the current that can flow out of an output pin in the high-level state without reducing the output voltage below the specified Voh. (A negative current indicates current flowing out of the pin.)

2.3 Electrical Specifications

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Power supply voltage	V _{DD33}		−0.5 to +4.6	V
	V _{DD25}		−0.5 to +3.6	V
	AV _{DD}		−0.5 to +3.6	V
Input/output voltage	Vı/Vo			
2.5 V input/output voltage		$2.3 \text{ V} \le \text{V}_{DD25} \le 2.7 \text{ V}$ V ₁ /V ₀ < V _{DD25} + 0.9 V	-0.5 to +3.6	V
3.3 V input/output voltage		3.0 V ≤ V _{DD33} ≤ 3.6 V V _I /V _O < V _{DD33} + 1.0 V	-0.5 to +4.6	V
5 V input/out voltage		3.0 V ≤ V _{DD33} ≤ 3.6 V V _I /V _O < V _{DD33} + 3.0 V	-0.5 to +6.6	V
Output current	lo	IoL = 3 mA IoL = 6 mA IoL = 12 mA	10 20 40	mA mA mA
Operating temperature	TA		0 to +70	°C
Storage temperature	Tstg		-65 to +150	°C

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameters. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

The ratings and conditions indicated for DC characteristics and AC characteristics represent the quality assurance range during normal operation.

Data Sheet S16618EJ3V0DS



Recommended Operating Ranges

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Operating voltage	V _{DD33}	3.3 V for V _{DD33} pins	3.14	3.30	3.46	٧
	V _{DD25}	2.5 V for V _{DD25} pins	2.3	2.5	2.7	V
	AV _{DD}	2.5 V for AV _{DD} pins	2.3	2.5	2.7	V
High-level input voltage	VIH					
2.5 V High-level input voltage			1.7		V _{DD25}	V
3.3 V High-level input voltage			2.0		V _{DD33}	V
5.0 V High-level input voltage			2.0		5.5	V
Low-level input voltage	VIL					
2.5 V Low-level input voltage			0		0.7	V
3.3 V Low-level input voltage			0		0.8	V
5.0 V Low-level input voltage			0		0.8	V
Hysteresis voltage	Vн					
5 V Hysteresis voltage			0.3		1.5	V
3.3 V Hysteresis voltage			0.2		1.0	V
Input rise time for SYSRSTB	trst				10	ms
Input rise time	tri					
Normal buffer			0		200	ns
Schmitt buffer			0		10	ms
Input fall time	t fi					
Normal buffer			0		200	ns
Schmitt buffer			0		10	ms

Two power supply rails limitation.

The μ PD720113 has two power supply rails (2.5 V, 3.3 V). The system will require the time when power supply rail is stable at V_{DD} level. And, there will be difference between the time of V_{DD25} and V_{DD33}. The μ PD720113 requires that V_{DD25} should be stable before V_{DD33} becomes stable. At any case, the system must ensure that the absolute maximum ratings for V₁/V₀ are not exceeded. System reset signaling should be asserted more than specified time after both V_{DD25} and V_{DD33} are stable.



DC Characteristics

Parameter	Symbol	Condition	MIN.	MAX.	Unit
Off-state output leakage current	loz	Vo = V _{DD33} , V _{DD25} or Vss		±10	μΑ
Output short circuit current	los ^{Note}			-250	mA
Low-level output current	loL				
3.3 V low-level output current		V _{OL} = 0.4 V	3		mA
3.3 V low-level output current		V _{OL} = 0.4 V	6		mA
5.0 V low-level output current		V _{OL} = 0.4 V	12		mA
High-level output current	Іон				
3.3 V high-level output current		V _{OH} = 2.4 V	-3		mA
3.3 V high-level output current		V _{OH} = 2.4 V	-6		mA
5.0 V high-level output current		V _{OH} = 2.4 V	-2		mA
Input leakage current	lı				
3.3 V buffer		V _I = V _{DD} or V _{SS}		±10	μΑ
5.0 V buffer		V _I = V _{DD} or V _{SS}		±10	μΑ

Note The output short circuit time is measured at one second or less and is tested with only one pin on the LSI.

Data Sheet S16618EJ3V0DS



USB Interface Block

Parameter	Symbol	Conditions	MIN	MAX	Unit
Output pin impedance	ZHSDRV	Includes Rs resistor	40.5	49.5	Ω
Bus pull-up resistor on upstream facing port	Reu		1.425	1.575	kΩ
Bus pull-up resistor on downstream facing port	RPD		14.25	15.75	kΩ
Termination voltage for upstream facing port pullup (full-speed)	VTERM		3.0	3.6	V
Input Levels for Low-/full-speed:					
High-level input voltage (drive)	ViH		2.0		V
High-level input voltage (floating)	VIHZ		2.7	3.6	V
Low-level input voltage	VIL			0.8	V
Differential input sensitivity	Vdl	(D+) – (D–)	0.2		V
Differential common mode range	Vсм	Includes V _{DI} range	0.8	2.5	V
Output Levels for Low-/full-speed:					
High-level output voltage	Vон	R _L of 14.25 kΩ to GND	2.8	3.6	V
Low-level output voltage	Vol	R∟ of 1.425 kΩ to 3.6 V	0.0	0.3	V
SE1	Vose1		0.8		V
Output signal crossover point voltage	Vcrs		1.3	2.0	V
Input Levels for High-speed:					
High-speed squelch detection threshold (differential signal)	VHSSQ		100	150	mV
High-speed disconnect detection threshold (differential signal)	VHSDSC		525	625	mV
High-speed data signaling common mode voltage range	VHSCM		-50	+500	mV
High-speed differential input signaling levels	See Figure	e 2-4.			
Output Levels for High-speed:	•				
High-speed idle state	VHSOI		-10.0	+10	mV
High-speed data signaling high	Vнsон		360	440	mV
High-speed data signaling low	VHSOL		-10.0	+10	mV
Chirp J level (different signal)	Vchirpj		700	1100	mV
Chirp K level (different signal)	Vchirpk		-900	-500	mV

Figure 2-1. Differential Input Sensitivity Range for Low-/full-speed

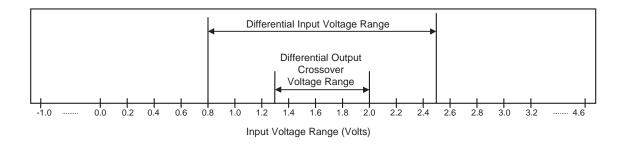


Figure 2-2. Full-speed Buffer VoH/loH Characteristics for High-speed Capable Transceiver

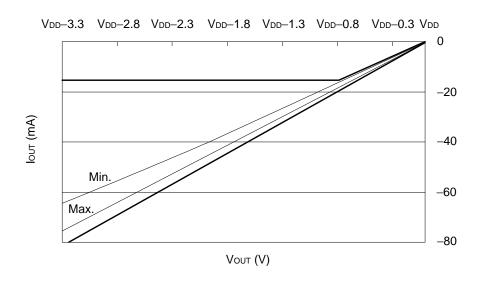
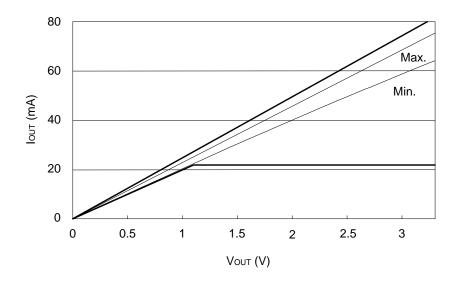


Figure 2-3. Full-speed Buffer Vol/loL Characteristics for High-speed Capable Transceiver



Data Sheet S16618EJ3V0DS

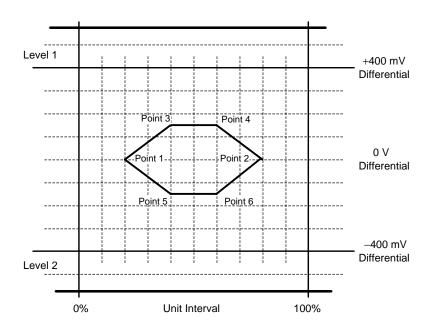
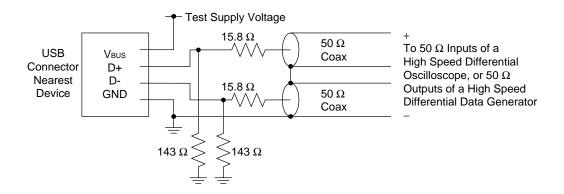


Figure 2-4. Receiver Sensitivity for Transceiver at DP/DM

Figure 2-5. Receiver Measurement Fixtures





Power Consumption

Parameter	Symbol	Condition	TYP.	Unit
Power Consumption	Pw-0	The power consumption under the state without suspend. All the ports do not connect to any function. Note		
		Hub controller is operating at full-speed mode.	44	mA (2.5 V)
			2.2	mA (3.3 V)
		Hub controller is operating at high-speed mode.	84	mA (2.5 V)
			23	mA (3.3 V)
	Pw-5	The power consumption under the state without suspend. The number of active ports is 5.		
		Hub controller is operating at full-speed mode.	44	mA (2.5 V)
			8.9	mA (3.3 V)
		Hub controller is operating at high-speed mode.	138	mA (2.5 V)
			85	mA (3.3 V)
	Pw-6	The power consumption under the state without suspend. The number of active ports is 6.		
		Hub controller is operating at full-speed mode.	44	mA (2.5 V)
			10	mA (3.3 V)
		Hub controller is operating at high-speed mode.	148	mA (2.5 V)
			98	mA (3.3 V)
	Pw-7	The power consumption under the state without suspend. The number of active ports is 7.		
		Hub controller is operating at full-speed mode.	44	mA (2.5 V)
			12	mA (3.3 V)
		Hub controller is operating at high-speed mode.	158	mA (2.5 V)
			111	mA (3.3 V)
	Pw_s	The power consumption under suspend state.	0.68	mA (2.5 V)
		The internal clock is stopped.	0.24	mA (3.3 V)

Note When any device is not connected to all the ports, the power consumption does not depend on the number of active ports.

Data Sheet S16618EJ3V0DS



System Clock Ratings

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Clock frequency	fclk	X'tal	–500 ppm	30	+500 ppm	MHz
		Oscillator block	–500 ppm	30	+500 ppm	MHz
Clock Duty cycle	t DUTY		40	50	60	%

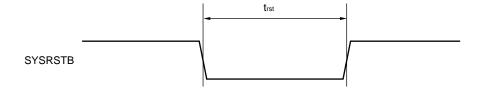
- **Remarks 1.** Recommended accuracy of clock frequency is \pm 100 ppm.
 - **2.** Required accuracy of X'tal or oscillator block is including initial frequency accuracy, the spread of X'tal capacitor loading, supply voltage, temperature, and aging, etc.

AC Characteristics (VDD = 3.14 to 3.46 V, TA = 0 to +70°C)

System Reset Timing

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Reset active time (Figure 2-6)	trst		5		μs

Figure 2-6. System Reset Timing



17



Over-current Response Timing

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Over-current response time from CSB low to PPB high (Figure 2-7)	toc		500		625	μs

Figure 2-7. Over-current Response Timing

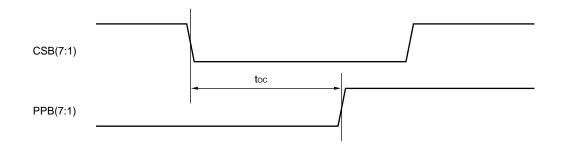
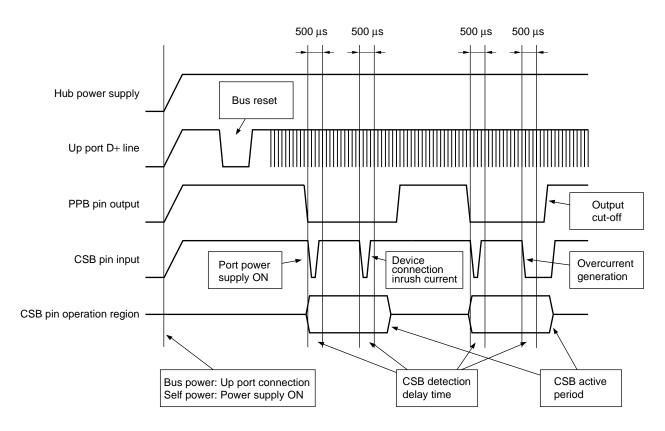


Figure 2-8. CSB/PPB Timing



Remark The active period of the CSB pin is in effect only when the PPB pin is ON. There is a delay time of approximately 500 μ s duration at the CSB pin.

Data Sheet S16618EJ3V0DS

External Serial ROM Timing

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Clock frequency	f scL			94.6	100	kHz
Clock pulse width low	tLow		4700			ns
Clock pulse width high	t HIGH		4000			ns
Clock low to data out valid	taa		100		3500	ns
Time the bus must be free before a new transmission can start	tbuf		4700			ns
Start hold time	thd.sta		4000			ns
Start setup time	tsu.sta		4700			ns
Data in hold time	t hd.dta		0			ns
Data in setup time	tsu.dta		250			ns
Stop setup time	tsu.sto		4700			ns
Data out hold time	t DH		300			ns
Write cycle time	twr				15	ms

Figure 2-9. External Serial ROM Bus Timing

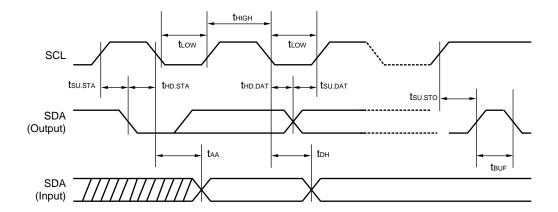
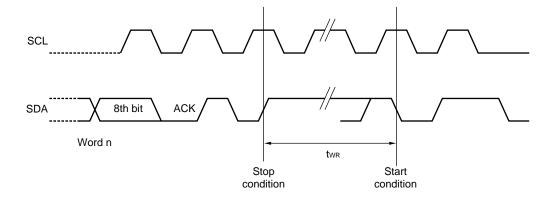


Figure 2-10. External Serial ROM Write Cycle Timing





USB Interface Block

(1/4)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Low-speed Electrical Characteristics					
Rise time (10% to 90%)	t LR	C _L = 200 pF to 600 pF	75	300	ns
Fall time (90% to 10%)	tlf	C _L = 200 pF to 600 pF	75	300	ns
Differential rise and fall time matching	turfm	(tlr/tlf) Note	80	125	%
Low-speed data rate	t ldraths	Average bit rate	1.49925	1.50075	Mbps
Downstream facing port source jitter total (including frequency tolerance) (Figure 2-15):	•		25	.25	
To next transition For paired transitions	todus todus		-25 -14	+25 +14	ns ns
Downstream facing port differential receiver jitter total (including frequency tolerance) (Figure 2-17): To next transition For paired transitions	tuuri tuuri		-152 -200	+152 +200	ns ns
Source SE0 interval of EOP (Figure 2-16)	t LEOPT		1.25	1.5	μS
Receiver SE0 interval of EOP (Figure 2-16)	t LEOPR		670		ns
Width of SE0 interval during differential transition	t lst			210	ns
Hub differential data delay (Figure 2-13)	t LHDD			300	ns
Hub differential driver jitter (including cable) (Figure 2-13): Downstream facing port					
To next transition For paired transitions	tldhj1		-45 -15	+45 +15	ns ns
Upstream facing port To next transition For paired transitions	tгини1 tгини2		-45 -45	+45 +45	ns ns
Data bit width distortion after SOP (Figure 2-13)	t lsop		-60	+60	ns
Hub EOP delay relative to tho (Figure 2-14)	t leopd		0	200	ns
Hub EOP output width skew (Figure 2-14)	t LHESK		-300	+300	ns
Full-speed Electrical Characteristics					
Rise time (10% to 90%)	tfR	C _L = 50 pF, Rs = 36 Ω	4	20	ns
Fall time (90% to 10%)	tff	C _L = 50 pF, Rs = 36 Ω	4	20	ns
Differential rise and fall time matching	t frfm	(tfr/tff)	90	111.11	%
Full-speed data rate	t fdraths	Average bit rate	11.9940	12.0060	Mbps
					<u> </u>

Note Excluding the first transition from the Idle state.

(2/4)

					(2/4)
Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Full-speed Electrical Characteristics (Con	tinued)				
Consecutive frame interval jitter	t rfi	No clock adjustment		42	ns
Source jitter total (including frequency tolerance) (Figure 2-15): To next transition	t _{DJ1}	Note	-3.5	+3.5	ns
For paired transitions	t _{DJ2}		-4.0	+4.0	ns
Source jitter for differential transition to SE0 transition (Figure 2-16)	t FDEOP		-2	+5	ns
Receiver jitter (Figure 2-17): To Next Transition For Paired Transitions	tur1 tur2		–18.5 –9	+18.5 +9	ns ns
Source SE0 interval of EOP (Figure 2-16)	t FEOPT		160	175	ns
Receiver SE0 interval of EOP (Figure 2-16)	t FEOPR		82		ns
Width of SE0 interval during differential transition	t FST			14	ns
Hub differential data delay (Figure 2-13) (with cable) (without cable)	thdd1 thdd2			70 44	ns ns
Hub differential driver jitter (including cable) (Figure 2-13): To next transition For paired transitions	t нду1 t нду2		-3 -1	+3 +1	ns ns
Data bit width distortion after SOP (Figure 2-13)	trsop		-5	+5	ns
Hub EOP delay relative to tho (Figure 2-14)	treopd		0	15	ns
Hub EOP output width skew (Figure 2-14)	t FHESK		-15	+15	ns
High-speed Electrical Characteristics				•	
Rise time (10% to 90%)	thsr		500		ps
Fall time (90% to 10%)	t HSF		500		ps
Driver waveform	See Figure	2-11.			<u> </u>
High-speed data rate	thsdrat		479.760	480.240	Mbps
Microframe interval	thsfram		124.9375	125.0625	μs
Consecutive microframe interval difference	thsrFi			4 high- speed	Bit times
Data source jitter	See Figure	2-11.		<u> </u>	
Receiver jitter tolerance	See Figure				
Hub data delay (without cable)	thshdd			36 high- speed+4 ns	Bit times
Hub data jitter	See Figure	2-4, Figure 2-11.			
Hub delay variation range	thshov			5 high- speed	Bit times

Note Excluding the first transition from the Idle state.

	1	1		1	(3/4)
Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Hub Event Timings					
Time to detect a downstream facing port connect event (Figure 2-19): Awake hub Suspended hub	t DCNN		2.5 2.5	2000 12000	μs μs
Time to detect a disconnect event at a hub's downstream facing port (Figure 2-18)	todis		2.0	2.5	μs
Duration of driving resume to a downstream port (only from a controlling hub)	torsmon		20		ms
Time from detecting downstream resume to rebroadcast	tursm			1.0	ms
Duration of driving reset to a downstream facing port (Figure 2-20)	t DRST	Only for a SetPortFeature (PORT_RESET) request	10	20	ms
Time to detect a long K from upstream	turlk		2.5	100	μs
Time to detect a long SE0 from upstream	turlse0		2.5	10000	μs
Duration of repeating SE0 upstream (for low-/full-speed repeater)	turpse0			23	FS Bit times
Inter-packet delay (for high-speed) of packets traveling in same direction	thsipdsd		88		Bit times
Inter-packet delay (for high-speed) of packets traveling in opposite direction	thsipdod		8		Bit times
Inter-packet delay for device/root hub response with detachable cable for high-speed	thsrspipd1			192	Bit times
Time of which a Chirp J or Chirp K must be continuously detected (filtered) by hub or device during Reset handshake	t FILT		2.5		μs
Time after end of device Chirp K by which hub must start driving first Chirp K in the hub's chirp sequence	t wтосн			100	μs
Time for which each individual Chirp J or Chirp K in the chirp sequence is driven downstream by hub during reset	tосныт		40	60	μs
Time before end of reset by which a hub must end its downstream chirp sequence	tDCHSE0		100	500	μs
Time from internal power good to device pulling D+ beyond V _{IHZ} (Figure 2-20)	tsigatt			100	ms
Debounce interval provided by USB system software after attach (Figure 2-20)	t attdb			100	ms
Maximum duration of suspend averaging interval	tsusavgi			1	S
Period of idle bus before device can initiate resume	twtrsm		5		ms
Duration of driving resume upstream	t _{DRSMUP}		1	15	ms

(4/4)

	1		1	•	(4/4)
Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Hub Event Timings (Continued)					
Resume recovery time	trsmrcy	Remote-wakeup is enabled	10		ms
Time to detect a reset from upstream for non high-speed capable devices	t DETRST		2.5	10000	μs
Reset recovery time (Figure 2-20)	trstrcy			10	ms
Inter-packet delay for full-speed	tipd		2		Bit times
Inter-packet delay for device response with detachable cable for full-speed	trspipd1			6.5	Bit times
SetAddress() completion time	t dsetaddr			50	ms
Time to complete standard request with no data	†DRQCMPLTND			50	ms
Time to deliver first and subsequent (except last) data for standard request	tdretdata1			500	ms
Time to deliver last data for standard request	t DRETDATAN			50	ms
Time for which a suspended hub will see a continuous SE0 on upstream before beginning the high-speed detection handshake	tfiltse0		2.5		μs
Time a hub operating in non-suspended full-speed will wait after start of SE0 on upstream before beginning the high-speed detection handshake	twrrstfs		2.5	3000	ms
Time a hub operating in high-speed will wait after start of SE0 on upstream before reverting to full-speed	t wtrev		3.0	3.125	ms
Time a hub will wait after reverting to full- speed before sampling the bus state on upstream and beginning the high-speed will wait after start of SE0 on upstream before reverting to full-speed	twrrsths		100	875	ms
Minimum duration of a Chirp K on upstream from a hub within the reset protocol	tucн		1.0		ms
Time after start of SE0 on upstream by which a hub will complete its Chirp K within the reset protocol	tuchend			7.0	ms
Time between detection of downstream chip and entering high-speed state	twтнs			500	μs
Time after end of upstream Chirp at which hub reverts to full-speed default state if no downstream Chirp is detected	twtfs		1.0	2.5	ms

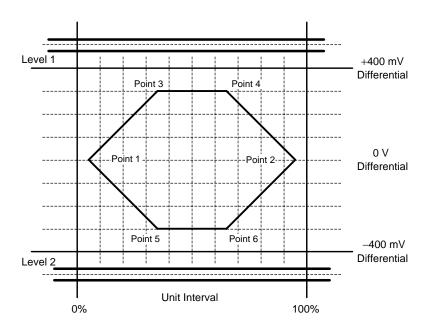
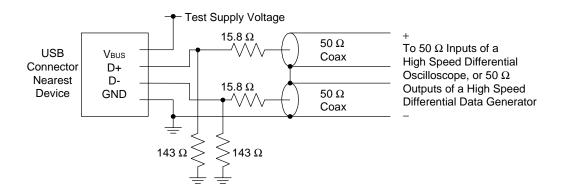


Figure 2-11. Transmit Waveform for Transceiver at DP/DM

Figure 2-12. Transmitter Measurement Fixtures

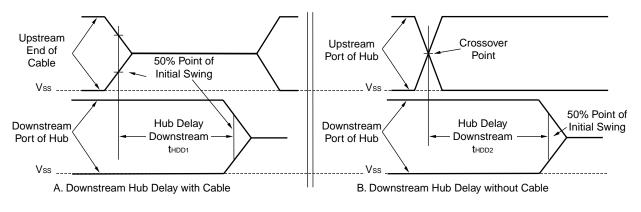


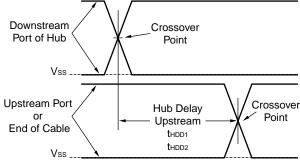
Data Sheet S16618EJ3V0DS 23



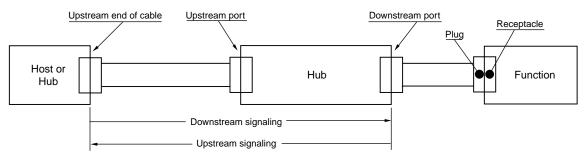
Timing Diagram

Figure 2-13. Hub Differential Delay, Differential Jitter, and SOP Distortion





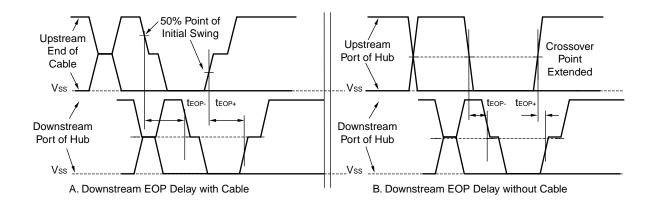
C. Upstream Hub Delay with or without Cable

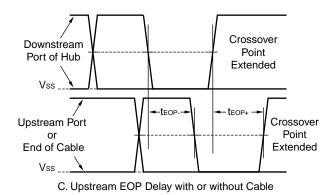


D. Measurement Points

Hub Differential Jitter: $thd_{J1} = thd_{DX}(J) - thd_{DX}(K) \text{ or } thd_{DX}(K) - thd_{DX}(J) \text{ Consecutive Transitions} \\ thd_{J2} = thd_{DX}(J) - thd_{DX}(J) \text{ or } thd_{DX}(K) - thd_{DX}(K) \text{ Paired Transitions} \\ Bit after SOP Width Distortion (same as data jitter for SOP and next J transition):} \\ tfsop = thd_{DX}(next J) - thd_{DX}(SOP) \\ Low-speed timings are determined in the same way for: \\ tlhd_{D}, tld_{HJ1}, tld_{HJ1}, tld_{HJ1}, tld_{HJ1}, tld_{HJ1}, tld_{HJ1}, and tlsop$

Figure 2-14. Hub EOP Delay and EOP Skew





EOP Delay:

 $t_{FEOPD} = t_{EOPy} - t_{HDDx}$

(teopy means that this equation applies to teop- and teop+)

EOP Skew:

 $t_{\text{FHESK}} = t_{\text{EOP+}} - t_{\text{EOP-}}$

Low-speed timings are determined in the same way for: tleopd and tlhesk

Data Sheet S16618EJ3V0DS

Figure 2-15. USB Differential Data Jitter for Low-/full-speed

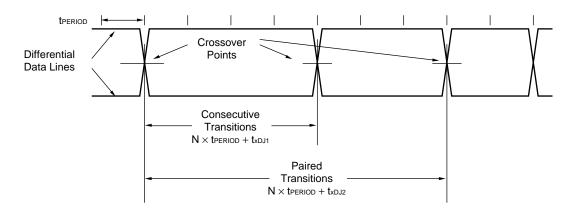


Figure 2-16. USB Differential-to-EOP Transition Skew and EOP Width for Low-/full-speed

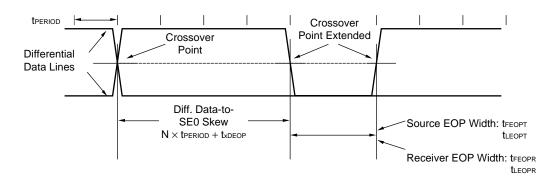


Figure 2-17. USB Receiver Jitter Tolerance for Low-/full-speed

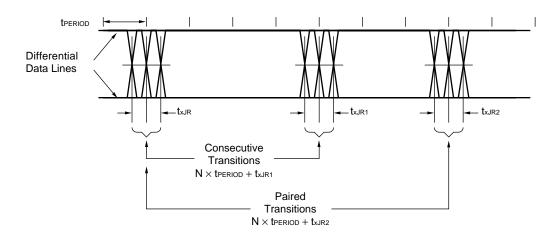


Figure 2-18. Low-/full-speed Disconnect Detection

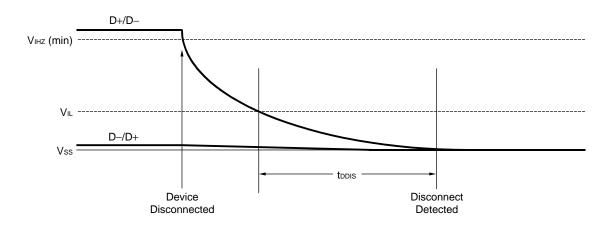


Figure 2-19. Full-/high-speed Device Connect Detection

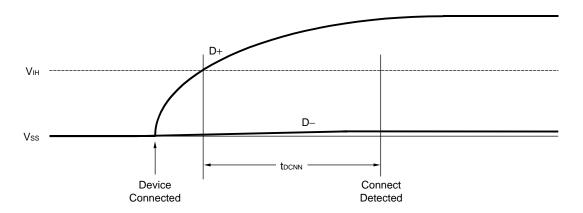
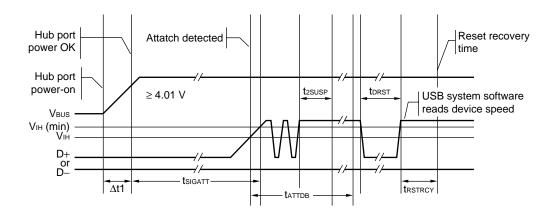


Figure 2-20. Power-on and Connection Events Timing

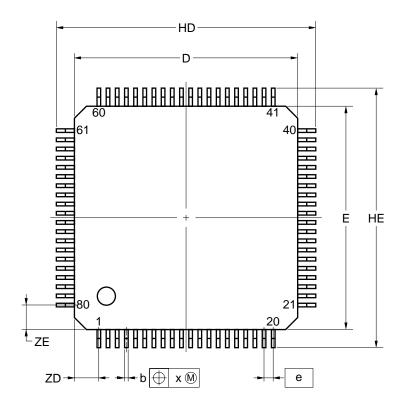


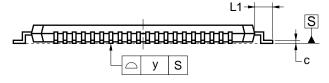
Data Sheet S16618EJ3V0DS



3. PACKAGE DRAWING

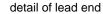
80-PIN PLASTIC TQFP (FINE PITCH) (12x12)

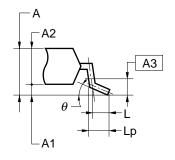




NOTE

Each lead centerline is located within 0.08 mm of its true position at maximum material condition.





(UNIT:mm)

ITEM	DIMENSIONS
D	12.00±0.20
Е	12.00±0.20
A2	1.00
HD	14.00±0.20
HE	14.00±0.20
Α	1.10±0.10
A1	0.10±0.05
A3	0.25
Lp	0.60±0.15
b	0.22±0.05
С	$0.17^{+0.03}_{-0.07}$
θ	3°+4°
е	0.50
х	0.08
У	0.08
ZD	1.25
ZE	1.25
L	0.50
L1	1.00±0.20
	K80GK-50-9EU

4. RECOMMENDED SOLDERING CONDITIONS

The μ PD720113 should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

 μ PD720113GK-9EU: 80-pin plastic TQFP (Fine pitch) (12 × 12)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher),	IR35-103-3
	Count: Three times or less	
	Exposure limit: 3 days ^{Note} (after that, prebake at 125°C for 10 hours)	
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	_

Note After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

μPD720113GK-9EU-A: 80-pin plastic TQFP (Fine pitch) (12 × 12) Lead-free product

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 245°C, Time: 60 seconds max. (at 220°C or higher),	IR45-107-3
	Count: Three times or less	
	Exposure limit: 7 days ^{Note} (after that, prebake at 125°C for 10 hours)	
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	_

Note After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

Data Sheet S16618EJ3V0DS 29



[MEMO]

NOTES FOR CMOS DEVICES —

(1) VOLTAGE APPLICATION WAVEFORM AT INPUT PIN

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between $V_{\rm IL}$ (MAX) and $V_{\rm IH}$ (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between $V_{\rm IL}$ (MAX) and $V_{\rm IH}$ (MIN).

(2) HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

③ PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

(4) STATUS BEFORE INITIALIZATION

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

(5) POWER ON/OFF SEQUENCE

In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current.

The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.

6 INPUT OF SIGNAL DURING POWER OFF STATE

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

USB logo is a trademark of USB Implementers Forum, Inc.

- The information in this document is current as of March, 2005. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets or data books, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without the prior
 written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may
 appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual
 property rights of third parties by or arising from the use of NEC Electronics products listed in this document
 or any other liability arising from the use of such products. No license, express, implied or otherwise, is
 granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of a customer's equipment shall be done under the full
 responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by
 customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality, reliability and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC Electronics products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment and anti-failure features.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and "Specific".
 - The "Specific" quality grade applies only to NEC Electronics products developed based on a customerdesignated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.
 - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).